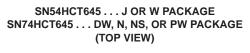
- Operating Voltage Range of 4.5 V to 5.5 V
- High-Current 3-State Outputs Can Drive Up To 15 LSTTL Loads
- Low Power Consumption, 80-μA Max I<sub>CC</sub>
- Typical t<sub>pd</sub> = 14 ns

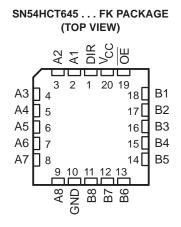


					1
DIR	ď	1	U	20	Vcc
A1		2		19	] OE
A2	[:	3		18	<b>]</b> B1
A3	<b>[</b>	4		17	<b>B</b> 2
A4	[	5		16	<b>]</b> B3
A5	[] (	6		15	<b>B</b> 4
A6		7		14	<b>B</b> 5
A7	[]	8		13	<b>]</b> B6
A8	<b>[</b>	9		12	<b>B</b> 7
GND	ſ	10		11	] B8

SN54HCT645, SN74HCT645 OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCLS019D - MARCH 1984 - REVISED AUGUST 2003

- ±6-mA Output Drive at 5 V
- Low Input Current of 1 μA Max
- Inputs Are TTL-Voltage Compatible
- True Logic



#### description/ordering information

These octal bus transceivers are designed for asynchronous two-way communication between data buses. These devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending upon the level at the direction-control (DIR) input. The output-enable ( $\overline{OE}$ ) input can be used to disable the device so the buses are effectively isolated.

T <sub>A</sub>	PACKA	GEŤ	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube of 20	SN74HCT645N	SN74HCT645N
		Tube of 25 SN74HCT645DW		1107045
	SOIC – DW	Reel of 2000	SN74HCT645DWR	HCT645
$-40^{\circ}$ C to $85^{\circ}$ C	SOP – NS	Reel of 2000	SN74HCT645NSR	HCT645
		Tube of 70	SN74HCT645PW	
	TSSOP – PW	Reel of 2000	SN74HCT645PWR	HT645
		Reel of 250	SN74HCT645PWT	
	CDIP – J	Tube of 20	SNJ54HCT645J	SNJ54HCT645J
–55°C to 125°C	CFP – W	Tube of 85	SNJ54HCT645W	SNJ54HCT645W
	LCCC – FK	Tube of 55	SNJ54HCT645FK	SNJ54HCT645FK

#### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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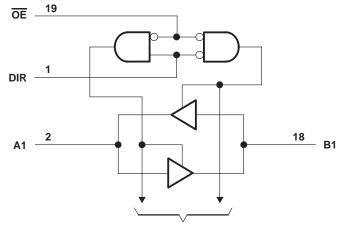
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### SN54HCT645, SN74HCT645 **OCTAL BUS TRANSCEIVERS** WITH 3-STATE OUTPUTS

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	FUNCTION TABLE										
INP	UTS										
OE	DIR	OPERATION									
L	L	B data to A bus									
L	Н	A data to B bus									
Н	Х	Isolation									

#### logic diagram (positive logic)



**To Seven Other Transceivers** 

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

	(see Note 1)
	±35 mA
	±70 mA
	DW package 58°C/W
	N package 69°C/W
I	NS package 60°C/W
	PW package
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



SCLS019D - MARCH 1984 - REVISED AUGUST 2003

#### recommended operating conditions (see Note 3)

			SN	54HCT6	45	SN	74HCT6	45	
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage		4.5	5	\$ 5.5	4.5	5	5.5	V
VIH	High-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2	L.		2			V
VIL	Low-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V		24	0.8			0.8	V
VI	Input voltage		0	1	VCC	0		VCC	V
VO	Output voltage		0	2	VCC	0		VCC	V
$\Delta t/\Delta v$	Input transition rise/fall time		0	5	500			500	ns
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

		TEAT OON			Т	A = 25°C	;	SN54H0	CT645	SN74H	CT645	
PAR	AMETER			v <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
Maria			I <sub>OH</sub> = -20 μA	451	4.4	4.499		4.4		4.4		V
VOH		$V_I = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		V
			I <sub>OL</sub> = 20 μA	4514		0.001	0.1		0.1		0.1	
VOL		$V_{I} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 6 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	V
I	DIR or OE	$V_{I} = V_{CC} \text{ or } 0$		5.5 V		±0.1	±100		±1000		±1000	nA
IOZ	A or B	$V_{O} = V_{CC} \text{ or } 0$		5.5 V		±0.01	±0.5	4	±10		±5	μΑ
ICC		$V_I = V_{CC} \text{ or } 0,$	IO = 0	5.5 V			8	200	160		80	μΑ
∆lCC‡	-	One input at 0.5 V c Other inputs at 0 or		5.5 V		1.4	2.4	PhO	3		2.9	mA
Ci	DIR or OE			4.5 V to 5.5 V		3	10		10		10	pF

<sup>†</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.

# switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	N.	Τį	ς = 25°C	;	SN54HCT645	SN74HCT645	LINUT
PARAMETER	(INPUT)	(OUTPUT)	vcc	MIN	TYP	MAX	MIN MAX	MIN MAX	UNIT
	A an D	DerA	4.5 V		16	22	33	28	
<sup>t</sup> pd	A or B	B or A	5.5 V		14	20	30	25	ns
	OE	A	4.5 V		25	46	69	58	
ten	OE	A or B	5.5 V		22	41	62	52	ns
	OE	A an D	4.5 V		26	40	60	50	
<sup>t</sup> dis	OE	A or B	5.5 V		23	36	<b>5</b> 4	45	ns
4.		A or B	4.5 V		9	12	18	15	20
tt		AUB	5.5 V		8	11	16	14	ns



### SN54HCT645, SN74HCT645 **OCTAL BUS TRANSCEIVERS** WITH 3-STATE OUTPUTS

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# switching characteristics over recommended operating free-air temperature range, $C_L = 150 \text{ pF}$ (unless otherwise noted) (see Figure 1)

	FROM	то		Т	ן = 25°C	;	SN54H0	CT645	SN74H	CT645	
PARAMETER	(INPUT)	(OUTPUT)	UT) V <sub>CC</sub>		TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	A an D	DerA	4.5 V		20	30		45		38	
<sup>t</sup> pd	A or B	B or A	5.5 V		18	27		G 41		34	ns
	OE	A an D	4.5 V		36	59	00	89		74	
<sup>t</sup> en	OE	A or B	5.5 V		30	53	5,56	80		67	ns
		A or B	4.5 V		17	42		63		53	
t		AOID	5.5 V		14	38		57		48	ns

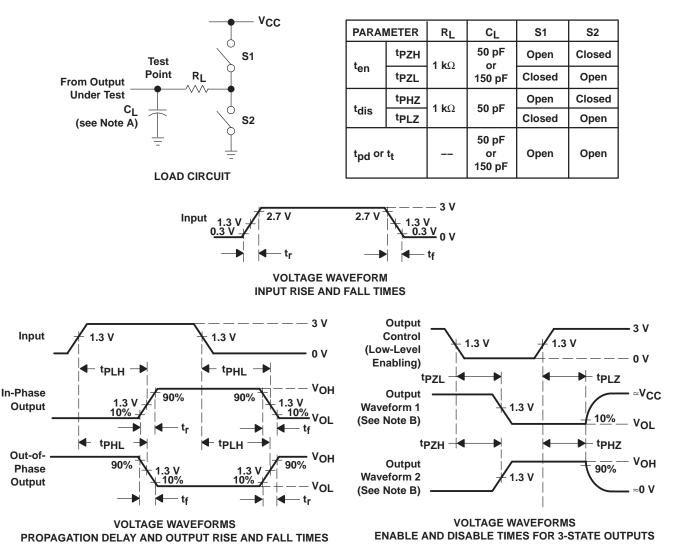
### operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
Cpd	Power dissipation capacitance per transceiver	No load	40	pF



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#### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. CL includes probe and test-fixture capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z<sub>Q</sub> = 50 Ω, t<sub>r</sub> = 6 ns, t<sub>f</sub> = 6 ns.
  - D. The outputs are measured one at a time with one input transition per measurement.
  - E. tPLZ and tPHZ are the same as tdis.
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G. tPLH and tPHL are the same as tpd.

#### Figure 1. Load Circuit and Voltage Waveforms





#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
SN74HCT645DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	HCT645	
SN74HCT645DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT645	Samples
SN74HCT645N	ACTIVE	PDIP	Ν	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT645N	Samples
SN74HCT645PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT645	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



1	All dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
Ĩ	SN74HCT645DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1



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### PACKAGE MATERIALS INFORMATION

16-Apr-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT645DWR	SOIC	DW	20	2000	367.0	367.0	45.0

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#### TUBE



### - B - Alignment groove width

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74HCT645N	N	PDIP	20	20	506	13.97	11230	4.32
SN74HCT645PW	PW	TSSOP	20	70	530	10.2	3600	3.5

### N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



### **DW0020A**



### **PACKAGE OUTLINE**

#### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



### DW0020A

### **EXAMPLE BOARD LAYOUT**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### DW0020A

### **EXAMPLE STENCIL DESIGN**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### **PW0020A**



### **PACKAGE OUTLINE**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



### PW0020A

### **EXAMPLE BOARD LAYOUT**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### PW0020A

### **EXAMPLE STENCIL DESIGN**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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